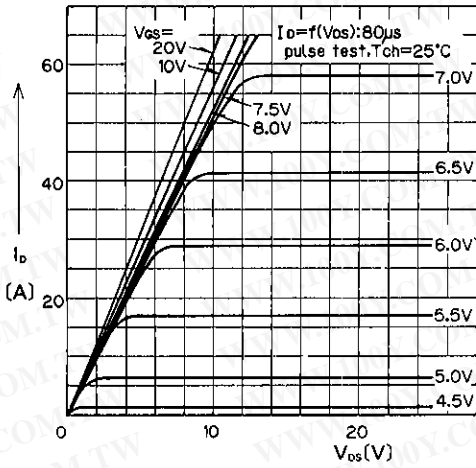
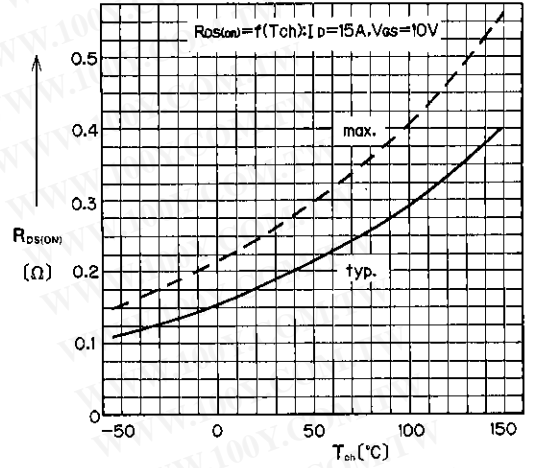


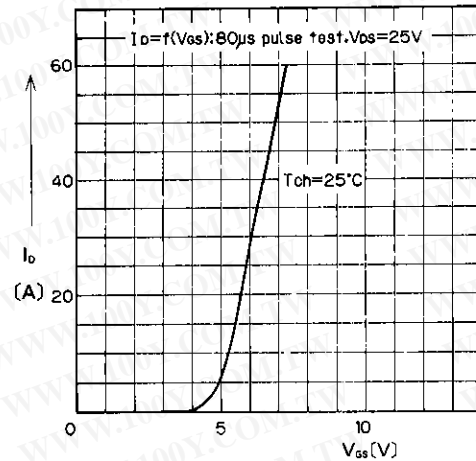
■ Characteristics



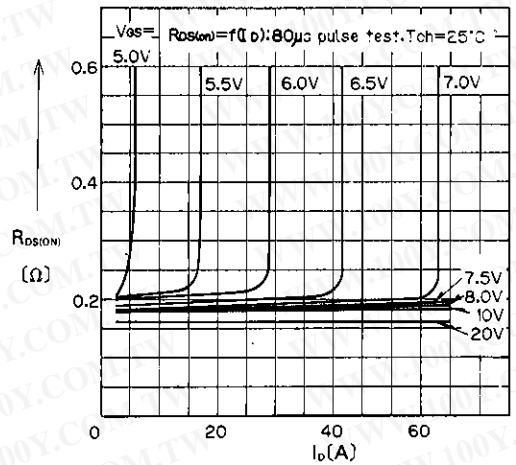
Typical Output Characteristics



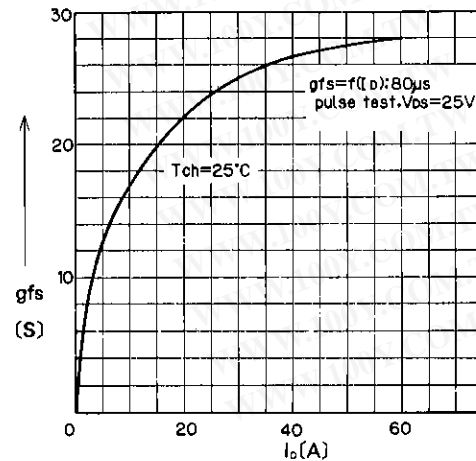
On State Resistance vs. Tch



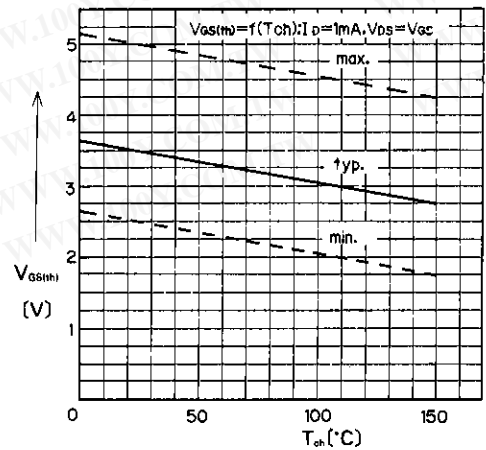
Typical Transfer Characteristics



Typical Drain-Source on State Resistance vs. Id



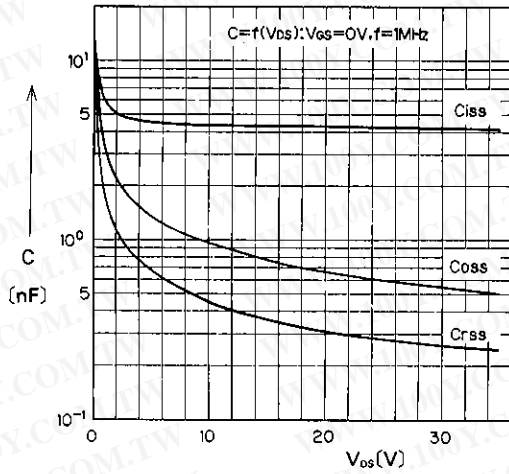
Typical Forward Transconductance vs. Id



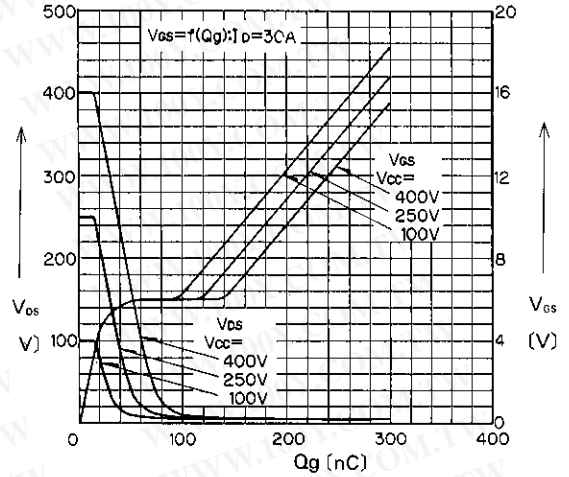
Gate Threshold Voltage vs. Tch

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 勝特力电子(深圳) 86-755-83298787
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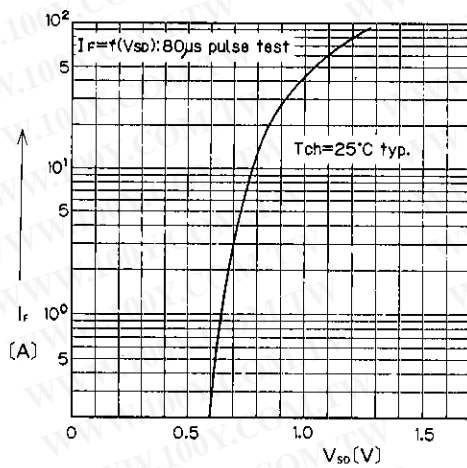
■ Characteristics



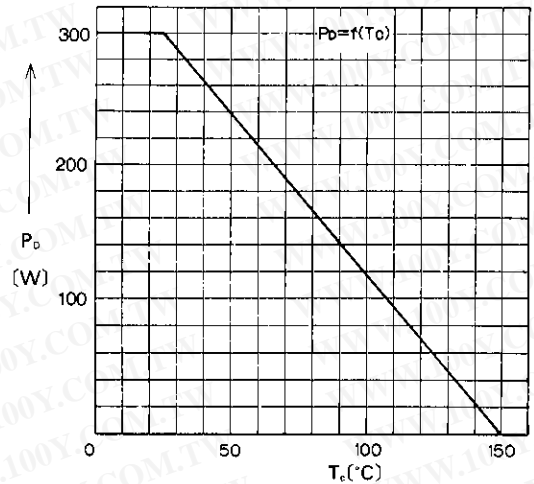
Typical Capacitance vs. V_{ds}



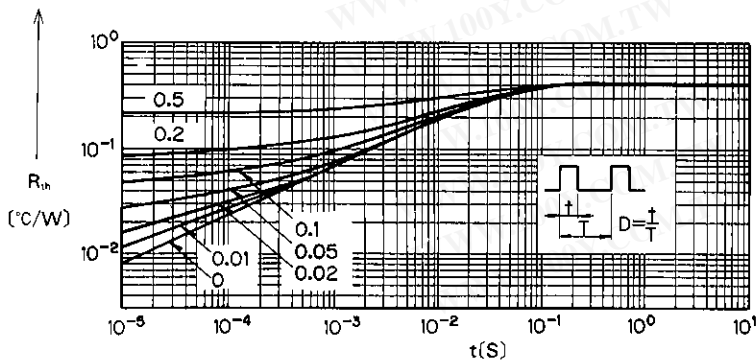
Typical Input Charge



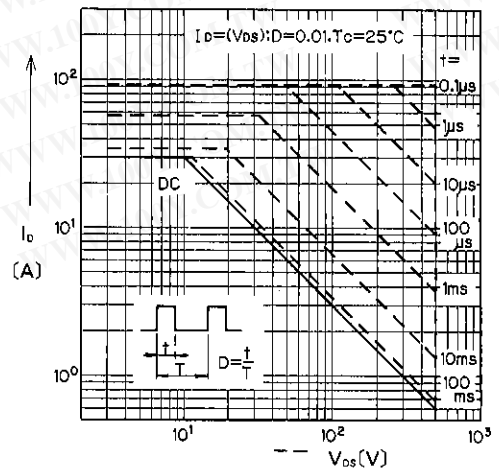
Forward Characteristics of Reverse Diode



Allowable Power Dissipation vs. T_c



Transient Thermal Impedance



Safe Operating Area